

Standard Diodes, 100 A (ADD-A-PAK Generation 5 Power Modules)



PRODUCT SUMMARY					
I _{F(AV)}	100 A				
Туре	Modules - Diode, High Voltage				

MECHANICAL DESCRIPTION

The Generation 5 of ADD-A-PAK module combine the excellent thermal performance obtained by the usage of direct bonded copper substrate with superior rmechanical ruggedness, thanks to the insertion of a solid copper baseplate at the bottom side of the device. The Cu baseplate allow an easier mounting on the majority of heatsink with increased tolerance of surface roughness and improve thermal spread.

The Generation 5 of AAP module is manufactured without hard mold, eliminating in this way any possible direct stress on the leads

The electrical terminals are secured against axial pull-out: they are fixed to the module housing via a click-stop feature already tested and proved as reliable on other Vishay HPP modules.

FEATURES

- High voltage
- Industrial standard package
- Thick copper baseplate
- UL E78996 approved
- 3500 V_{RMS} isolating voltage
- Compliant to RoHS directive 2002/95/EC
- · Designed and qualified for industrial level

BENEFITS

- Up to 1600 V
- Fully compatible TO-240AA
- · High surge capability
- · Easy mounting on heatsink
- Al₂O₃ DBC insulator
- · Heatsink grounded

ELECTRICAL DESCRIPTION

These modules are intended for general purpose high voltage applications such as high voltage regulated power supplies, lighting circuits, temperature and motor speed control circuits, UPS and battery charger.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
1		100	А			
I _{F(AV)}	T _C	100	°C			
I _{F(RMS)}		157				
I _{FSM}	50 Hz	2020	Α			
	60 Hz	2110				
l ² t	50 Hz	20.43	kA ² s			
FL	60 Hz	18.65	KA-S			
l²√t		204.3	kA ² √s			
V_{RRM}	Range	400 to 1600	V			
TJ		- 40 to 150	°C			
T _{Stg}						

Document Number: 94359 Revision: 20-May-10

VSK.91..PbF Series

Vishay Semiconductors

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ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS							
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = 150 °C mA			
	04	400	500				
	06	600	700				
	08	800	900				
VSK.91	10	1000	1100	10			
	12	1200	1300				
	14	1400	1500				
	16	1600	1700				

FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average forward current at case temperature	I _{F(AV)}	180° conduction, half sine wave			100 100	A °C
Maximum RMS forward current	I _{F(RMS)}	DC at 90 °C	case temperatui	re	157	
	, ,	t = 10 ms	No voltage		2020	
Maximum peak, one-cycle		t = 8.3 ms	reapplied		2110	Α
forward, non-repetitive surge current	I _{FSM}	t = 10 ms	100 % V _{RRM}		1700	
July Courtern		t = 8.3 ms	reapplied	Sinusoidal half wave,	1780	
Maximum I ² t for fusing	l ² t	t = 10 ms	No voltage	initial $T_J = T_J$ maximum	20.43	kA ² s
		t = 8.3 ms	reapplied		18.65	
		t = 10 ms	100 % V _{RRM}		14.45	
		t = 8.3 ms	reapplied		13.19	
Maximum $I^2\sqrt{t}$ for fusing	I²√t	t = 0.1 ms to	10 ms, no volta	ge reapplied	204.3	kA²√s
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % x π x	$\langle I_{F(AV)} \langle I \langle \pi \times I \rangle$	$F(AV)$, $T_J = T_J$ maximum	0.79	V
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi \times I_{F(AV)})$, Τ _J = Τ _J maximι	0.87	V	
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum			1.78	mΩ
High level value of forward slope resistance	r _{f2}	$(I > \pi \times I_{F(AV)})$, T _J = T _J maximu	1.57	11122	
Maximum forward voltage drop	V_{FM}	$I_{FM} = \pi \times I_{F(A)}$	_{V)} , T _J = 25 °C, t _p	= 400 µs square wave	1.45	V

BLOCKING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum peak reverse leakage current	I _{RRM}	T _J = 150 °C	10	mA			
RMS insulation voltage	V _{INS}	50 Hz, circuit to base, all terminals shorted	3500 (1 s)	V			



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THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL TEST CONDITIONS		VALUES	UNITS	
Maximum junction operating and storage temperature range		T _J , T _{Stg}		- 40 to 150	°C	
Maximum thermal resistance, junction to case per junction		R _{thJC}	DC operation	0.35	K/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface flat, smooth and greased	0.1		
Mounting torque ± 10 % busbar			A mounting compound is recommended and	5	Nino	
			the torque should be rechecked after a period of 3 hours to allow for the spread of the compound.	4	Nm	
Approximate weight				110	g	
Approximate weight				4	OZ.	
Case style			JEDEC	ADD-A-PAK	(TO-240AA)	

△R CONDUCTION PER JUNCTION											
DEVICES	S	SINE HALF WAVE CONDUCTION					RECTANGULAR WAVE CONDUCTION				UNITS
DEVICES	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	UNITS
VSK.91	0.052	0.064	0.082	0.112	0.164	0.043	0.069	0.088	0.115	0.165	°C/W

Note

 $\bullet \quad \text{Table shows the increment of thermal resistance } R_{\text{th}JC} \text{ when devices operate at different conduction angles than } DC$

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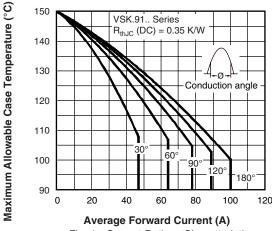


Fig. 1 - Current Ratings Characteristics

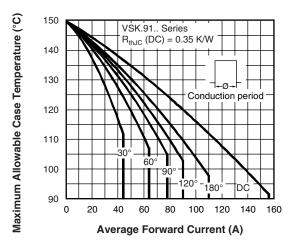


Fig. 2 - Current Ratings Characteristics

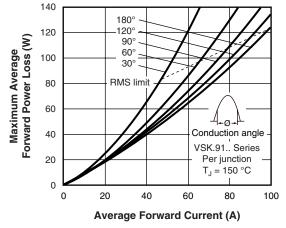


Fig. 3 - Forward Power Loss Characteristics

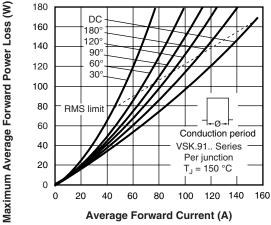
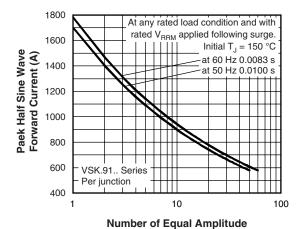


Fig. 4 - Foward Power Loss Characteristics



Half Cycle Current Pulses (N)
Fig. 5 - Maximum Non-Repetitive Surge Current

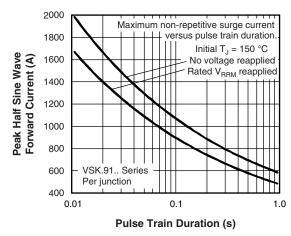
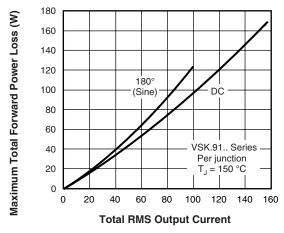


Fig. 6 - Maximum Non-Repetitive Surge Current



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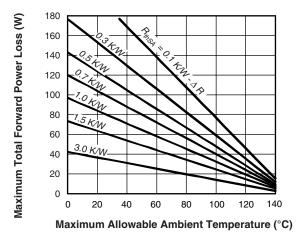
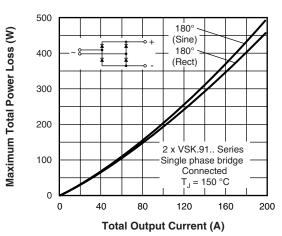


Fig. 7 - Forward Power Loss Characteristics



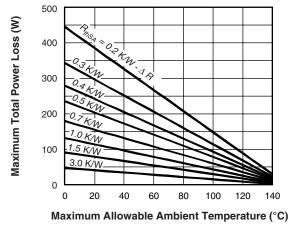
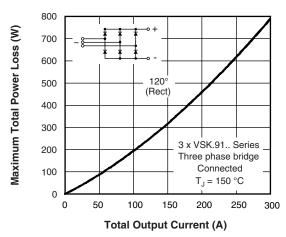


Fig. 8 - Forward Power Loss Characteristics



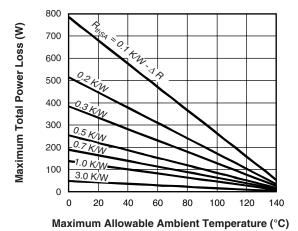


Fig. 9 - Forward Power Loss Characteristics

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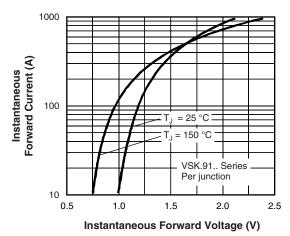


Fig. 10 - Forward Voltage Drop Characteristics

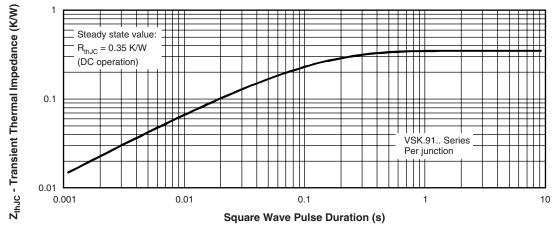


Fig. 11 - Thermal Impedance Z_{thJC} Characteristic

ORDERING INFORMATION TABLE

|1| - Module type

2 - Circuit configuration (see Circuit Configuration table)

3 - Current code

4 - Voltage code (see Voltage Ratings table)

5 - P = Lead (Pb)-free

Note

• To order the optional hardware go to www.vishay.com/doc?95172



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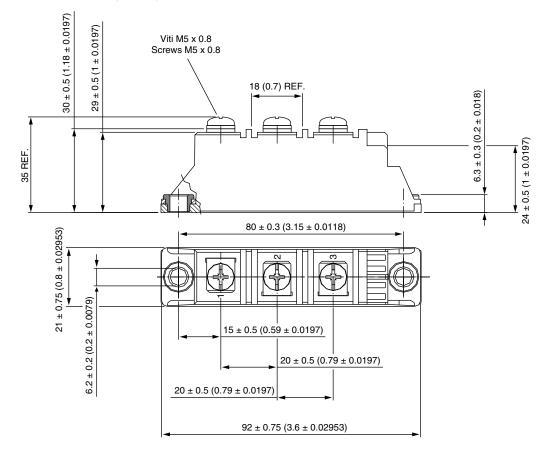
CIRCUIT CONFIGURATION						
CIRCUIT DESCRIPTION	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING				
		VSKD				
		(1) $\tilde{\circ}$ $\dot{\circ}$ (2) $\tilde{\circ}$ (3)				
Two diodes doubler circuit	D					
		VSKC				
	С	(1) 0 (2) (3)				
Two diodes common cathodes						
		VSKJ				
		(1) O + O (2) O (3)				
Two diodes common anodes	J					
		VSKE				
	E	(2) 0 (3)				
Single diode						

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95015			



ADD-A-PAK Diode

DIMENSIONS in millimeters (inches)



Document Number: 95015 Revision: 29-Sep-08

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